

MOSFETs Silicon P-Channel MOS (U-MOSVI)

SSM3J340R

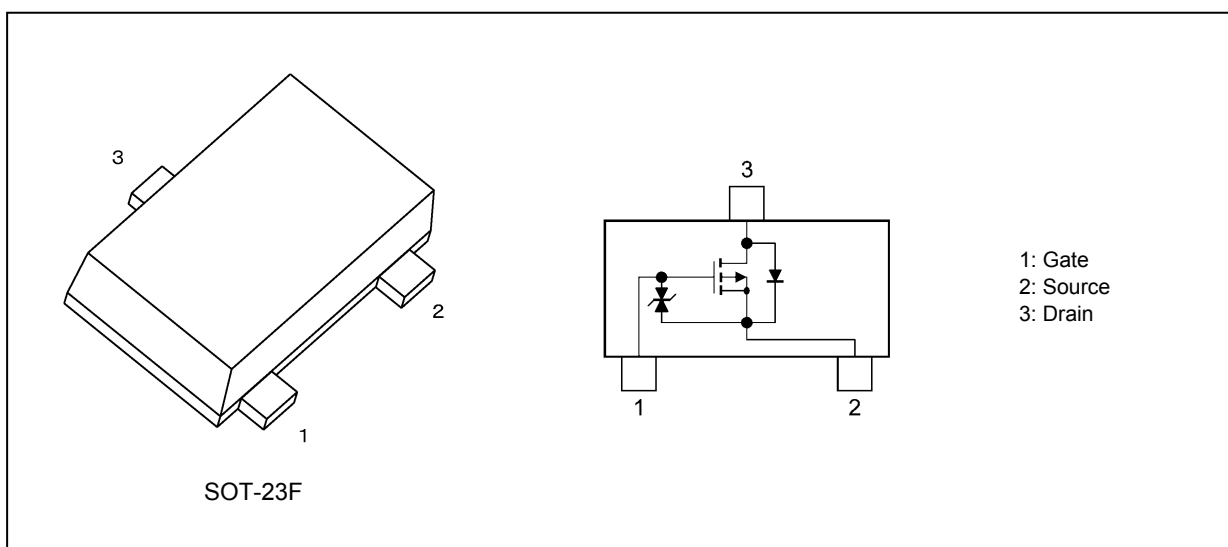
1. Applications

- Power Management Switches

2. Features

- (1) 4.0-V drive
- (2) Low drain-source on-resistance
 - : $R_{DS(ON)} = 86 \text{ m}\Omega$ (max) (@ $V_{GS} = -4.0 \text{ V}$)
 - $R_{DS(ON)} = 73 \text{ m}\Omega$ (max) (@ $V_{GS} = -4.5 \text{ V}$)
 - $R_{DS(ON)} = 45 \text{ m}\Omega$ (max) (@ $V_{GS} = -10 \text{ V}$)

3. Packaging and Pin Assignment



Start of commercial production
2016-03

4. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$)

| Characteristics | Symbol | Rating | Unit |
|---|-----------|------------|------------------|
| Drain-source voltage | V_{DSS} | -30 | V |
| Gate-source voltage | V_{GSS} | -25 / +20 | |
| Drain current (DC) (Note 1) | I_D | -4 | A |
| Drain current (pulsed) (Note 1), (Note 2) | I_{DP} | -12 | |
| Power dissipation (Note 3) | P_D | 1 | W |
| Power dissipation $t \leq 10\text{ s}$ (Note 3) | P_D | 2 | |
| Channel temperature | T_{ch} | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to 150 | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Ensure that the channel temperature does not exceed $150\text{ }^\circ\text{C}$.

Note 2: Repetitive rating; pulse width limited by maximum channel temperature.

Note 3: Device mounted on a $25.4\text{ mm} \times 25.4\text{ mm} \times 1.6\text{ mm}$ FR4 glass epoxy board (Cu pad: 645 mm^2)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance, $R_{th(ch-a)}$, and the drain power dissipation, P_D , vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

5. Electrical Characteristics

5.1. Static Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------------|---------------|--|------|------|---------|---------------|
| Gate leakage current | I_{GSS} | $V_{DS} = 0\text{ V}, V_{GS} = \pm 16\text{ V}$ | — | — | ± 1 | μA |
| Drain cut-off current | I_{DSS} | $V_{DS} = -30\text{ V}, V_{GS} = 0\text{ V}$ | — | — | -1 | |
| Drain-source breakdown voltage | $V_{(BR)DSS}$ | $I_D = -250\text{ }\mu\text{A}, V_{GS} = 0\text{ V}$ | -30 | — | — | V |
| Gate threshold voltage | V_{th} | $V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$ | -1.0 | — | -2.2 | |
| Drain-source on-resistance (Note 1) | $R_{DS(ON)}$ | $I_D = -1.0\text{ A}, V_{GS} = -4.0\text{ V}$ | — | 61 | 86 | m Ω |
| | | $I_D = -4.0\text{ A}, V_{GS} = -4.5\text{ V}$ | — | 55 | 73 | |
| | | $I_D = -4.0\text{ A}, V_{GS} = -10\text{ V}$ | — | 35 | 45 | |
| Forward transfer admittance (Note 1) | $ Y_{fs} $ | $V_{DS} = -10\text{ V}, I_D = -2.0\text{ A}$ | — | 7.1 | — | S |

Note 1: Pulse measurement.

5.2. Dynamic Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------|-----------|---|-----|------|-----|------|
| Input capacitance | C_{iss} | $V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V},$ $f = 1\text{ MHz}$ | — | 492 | — | pF |
| Reverse transfer capacitance | C_{rss} | | — | 75 | — | |
| Output capacitance | C_{oss} | | — | 97 | — | |
| Switching time (turn-on time) | t_{on} | $V_{DS} = -15\text{ V}, I_D = -2\text{ A},$ $V_{GS} = 0\text{ to }-4.5\text{ V}, R_G = 10\text{ }\Omega$ | — | 65 | — | ns |
| Switching time (turn-off time) | t_{off} | | — | 93 | — | |

5.3. Switching Time Test Circuit

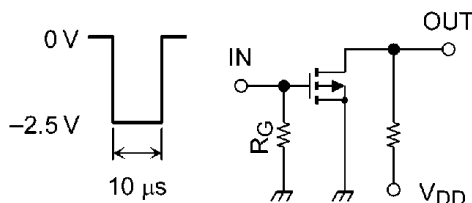


Fig. 5.3.1 Switching Time Test Circuit

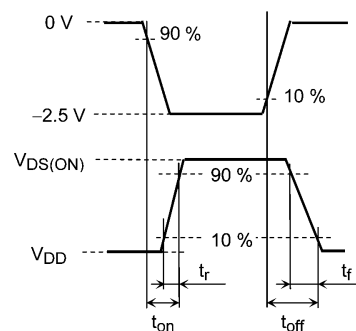


Fig. 5.3.2 Input Waveform/Output Waveform

5.4. Gate Charge Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$)

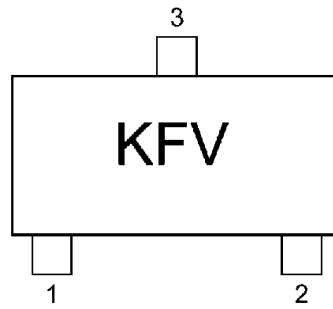
| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|---|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | Q_g | $V_{DD} = -15\text{ V}, I_D = -4.0\text{ A},$ $V_{GS} = -4.5\text{ V}$ | — | 6.2 | — | nC |
| Gate-source charge 1 | Q_{gs1} | | — | 1.5 | — | |
| Gate-drain charge | Q_{gd} | | — | 2.8 | — | |

5.5. Source-Drain Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------|-----------|---|-----|------|-----|------|
| Diode forward voltage (Note 1) | V_{DSF} | $I_D = 4.0\text{ A}, V_{GS} = 0\text{ V}$ | — | 0.85 | 1.1 | V |

Note 1: Pulse measurement.

6. Marking



7. Characteristics Curves (Note)

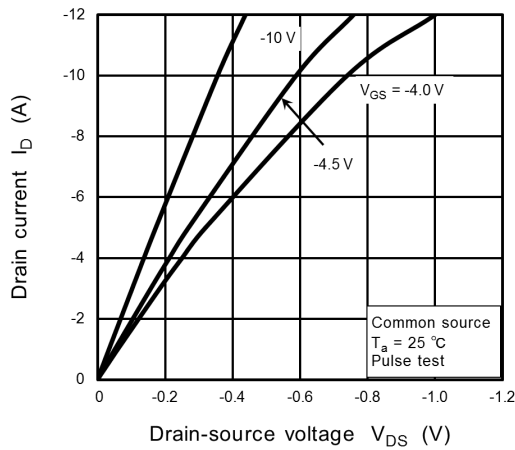


Fig. 7.1 $I_D - V_{DS}$

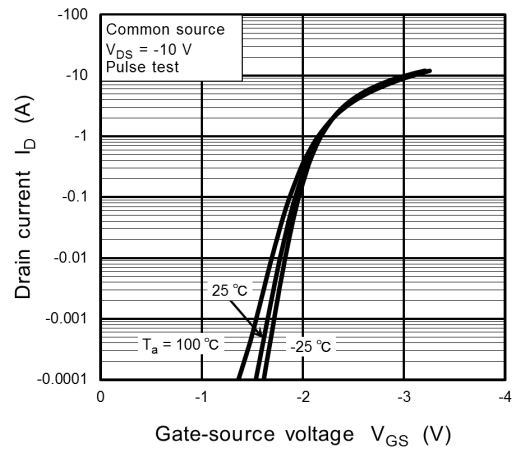


Fig. 7.2 $I_D - V_{GS}$

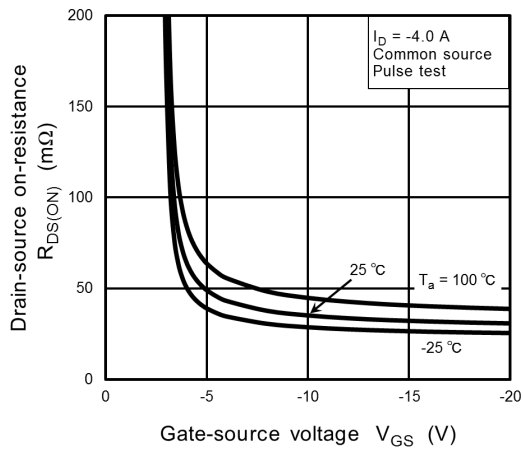


Fig. 7.3 $R_{DS(ON)} - V_{GS}$

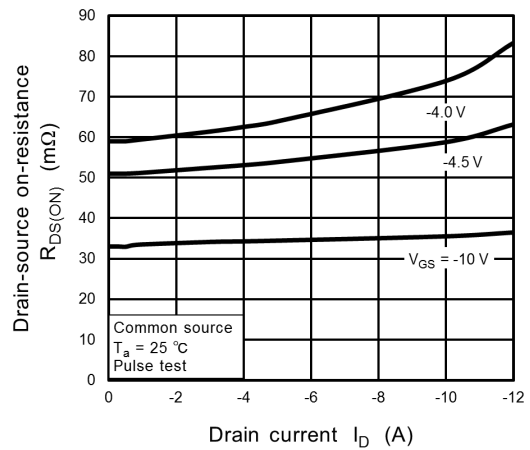


Fig. 7.4 $R_{DS(ON)} - I_D$

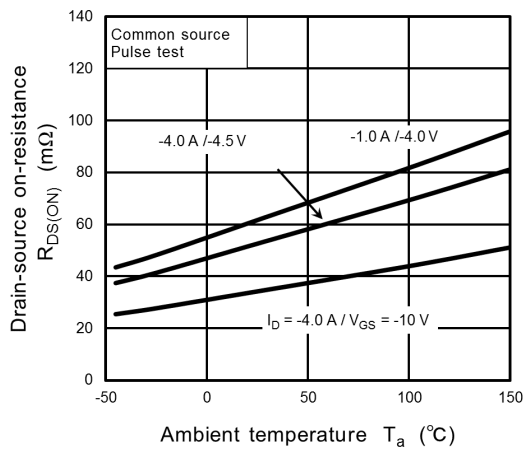


Fig. 7.5 $R_{DS(ON)} - T_a$

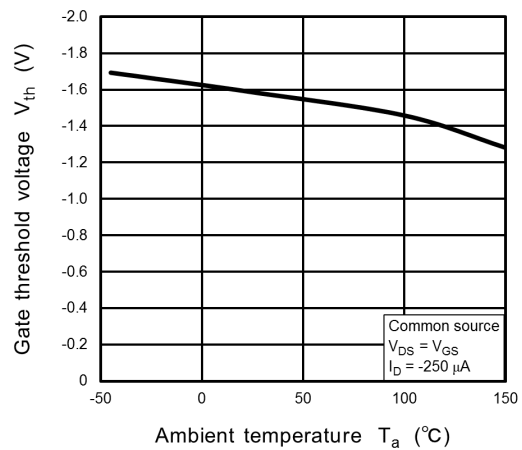


Fig. 7.6 $V_{th} - T_a$

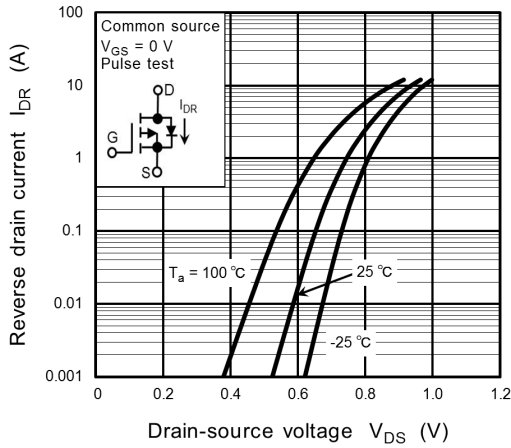


Fig. 7.7 $I_{DR} - V_{DS}$

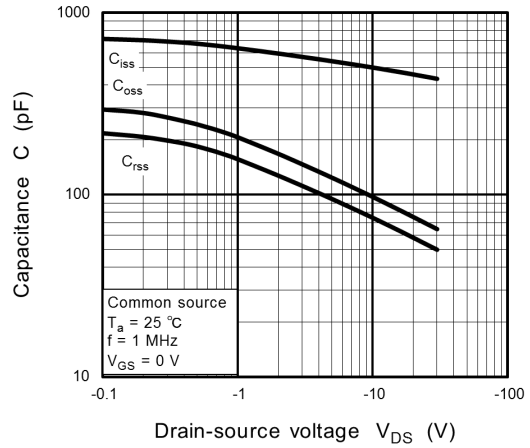


Fig. 7.8 $C - V_{DS}$

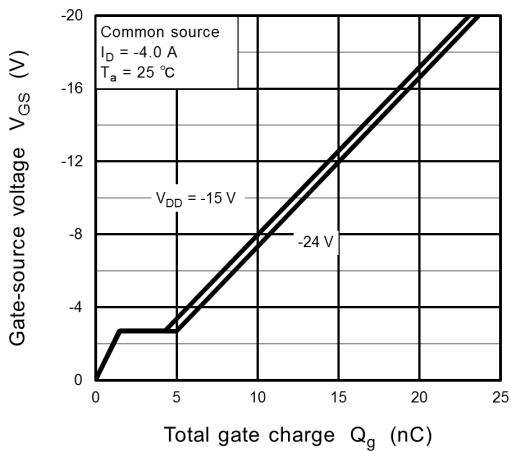


Fig. 7.9 Dynamic Input Characteristics

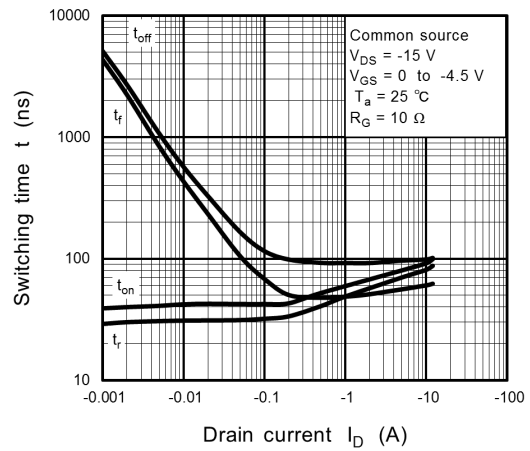


Fig. 7.10 $t - I_D$

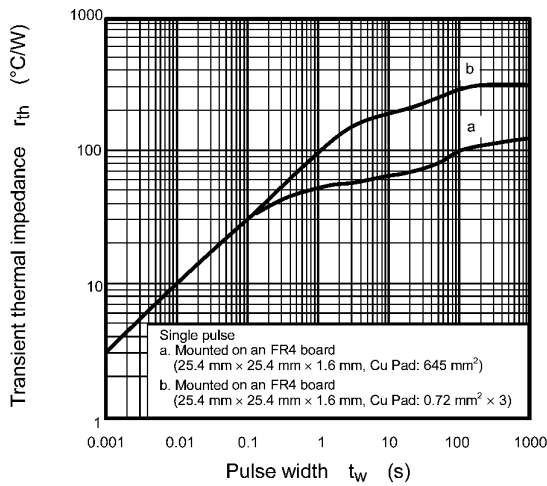


Fig. 7.11 $r_{th} - t_w$

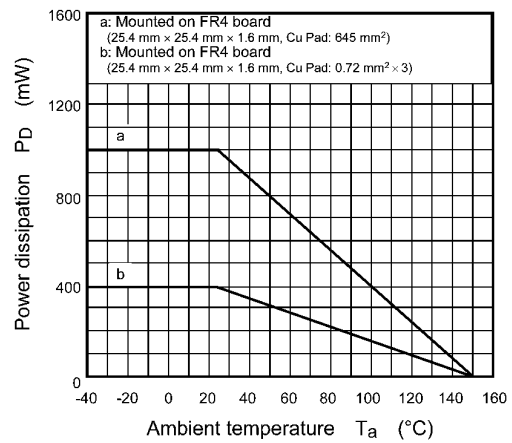
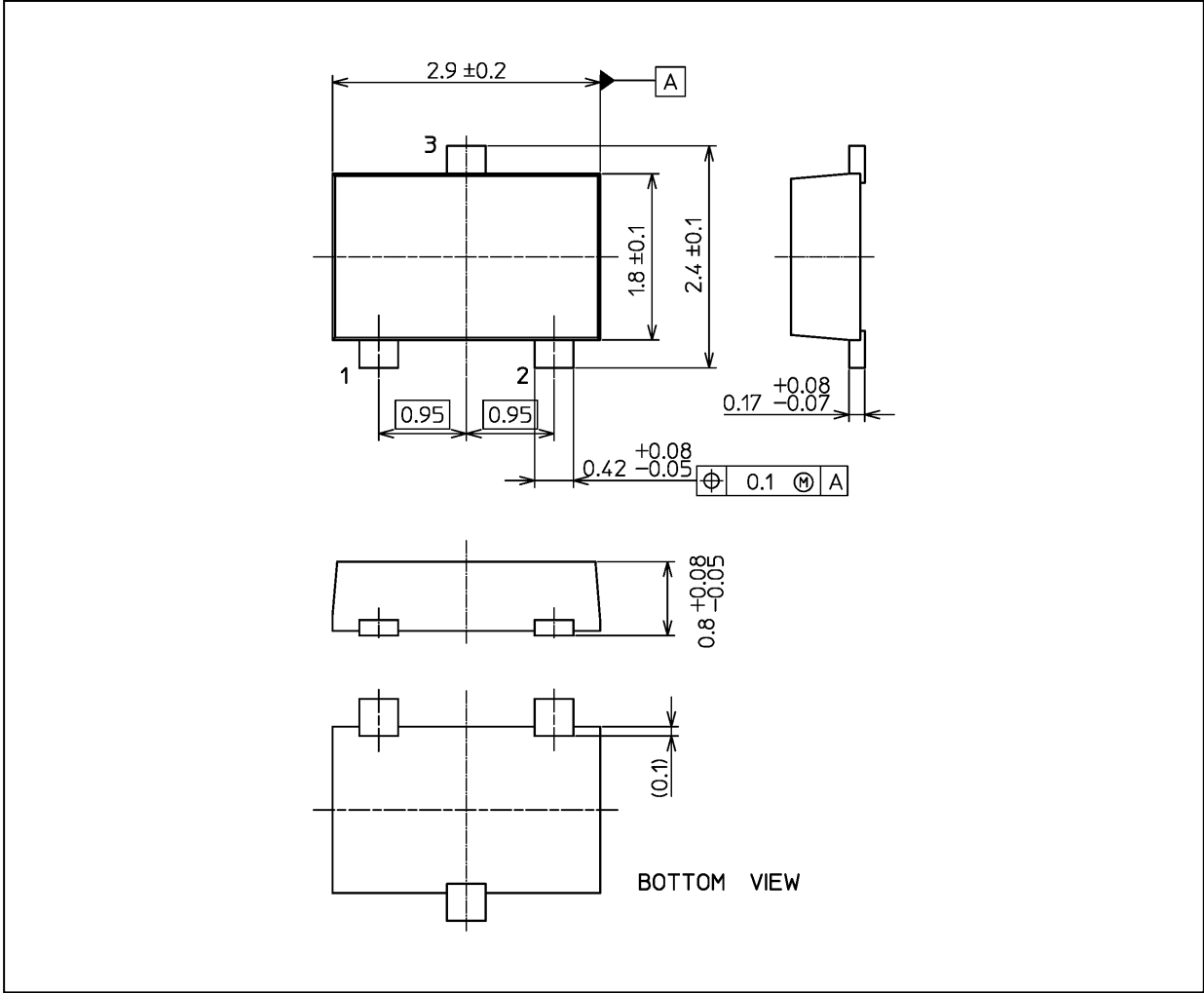


Fig. 7.12 $P_D - T_a$

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.011 g (typ.)

| |
|-------------------|
| Package Name(s) |
| Nickname: SOT-23F |

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